

# New Jersey Semi-Conductor Products, Inc.

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## Plastic NPN Silicon Medium-Power Transistors

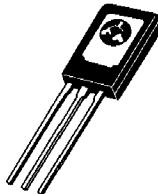
... useful for medium voltage applications requiring high  $f_T$  such as converters and extended range amplifiers.

### MAXIMUM RATINGS

Rating	Symbol	MJE341	MJE344	Unit
Collector-Emitter Voltage	$V_{CEO}$	150	200	Vdc
Collector-Base Voltage	$V_{CB}$	175	200	Vdc
Emitter-Base Voltage	$V_{EB}$	3.0	5.0	Vdc
Collector Current — Continuous	$I_C$	500		mAdc
Base Current	$I_B$	250		mAdc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	20 0.16		Watts $\text{W}/^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{Stg}$	-65 to +150		°C

**MJE341**  
**MJE344**

0.5 AMPERE  
POWER TRANSISTORS  
NPN SILICON  
150-200 VOLTS  
20 WATTS



TO-225AA TYPE

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$\theta_{JC}$	6.25	°C/W

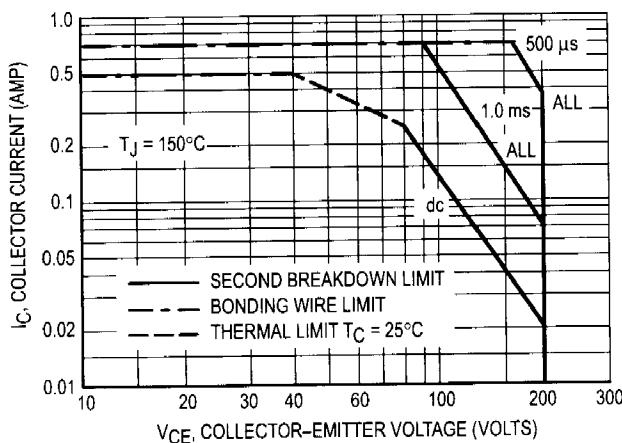


Figure 1. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on  $T_J(pk) = 150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_J(pk) \leq 150^\circ\text{C}$ . At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.



Quality Semi-Conductors

## MJE341 MJE344

ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Sustaining Voltage ( $I_C = 1.0 \text{ mA dc}, I_B = 0$ )	$V_{CEO(\text{sus})}$	150 200	—	Vdc
Collector Cutoff Current ( $V_{CE} = 150 \text{ Vdc}, I_B = 0$ ) ( $V_{CE} = 200 \text{ Vdc}, I_B = 0$ )	$I_{CEO}$	— —	1.0 1.0	mA dc
Collector Cutoff Current ( $V_{CB} = 175 \text{ Vdc}, I_E = 0$ ) ( $V_{CB} = 200 \text{ Vdc}, I_E = 0$ )	$I_{CBO}$	— —	0.3 0.1	mA dc
Emitter Cutoff Current ( $V_{EB} = 3.0 \text{ Vdc}, I_C = 0$ ) ( $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$ )	$I_{EBO}$	— —	0.1 0.1	mA dc
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = 10 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 50 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ ) ( $I_C = 150 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ )	$h_{FE}$	20 25 30 20	— 200 300 —	—
Collector-Emitter Saturation Voltage ( $I_C = 50 \text{ mA dc}, I_B = 5.0 \text{ mA dc}$ ) ( $I_C = 150 \text{ mA dc}, I_B = 15 \text{ mA dc}$ )	$V_{CE(\text{sat})}$	— —	1.0 2.3	Vdc
Base-Emitter On Voltage ( $I_C = 50 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}$ )	$V_{BE(\text{on})}$	—	1.0	Vdc
<b>DYNAMIC CHARACTERISTICS</b>				
Current-Gain — Bandwidth Product ( $I_C = 50 \text{ mA dc}, V_{CE} = 25 \text{ Vdc}, f = 10 \text{ MHz}$ )	$f_T$	15	—	MHz
Output Capacitance ( $V_{CB} = 20 \text{ Vdc}, I_E = 0, f = 100 \text{ kHz}$ )	$C_{ob}$	—	15	pF
Small-Signal Current Gain ( $I_C = 50 \text{ mA dc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$ )	$h_{fe}$	25	—	—

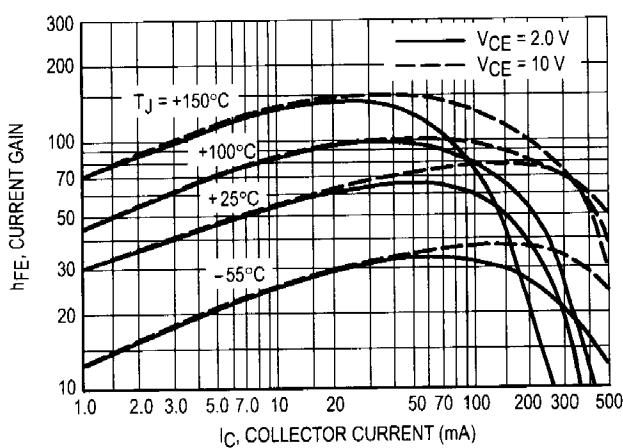


Figure 2. DC Current Gain

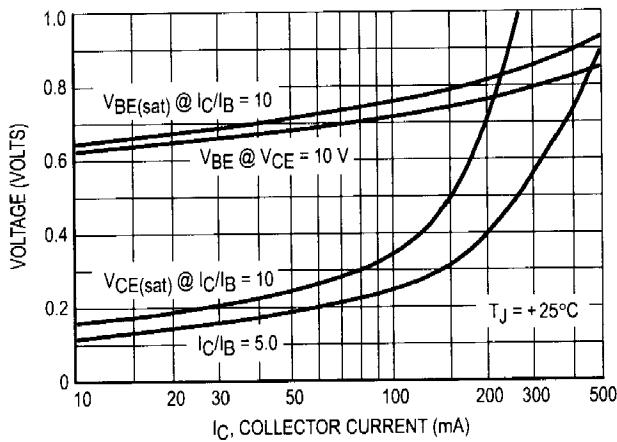
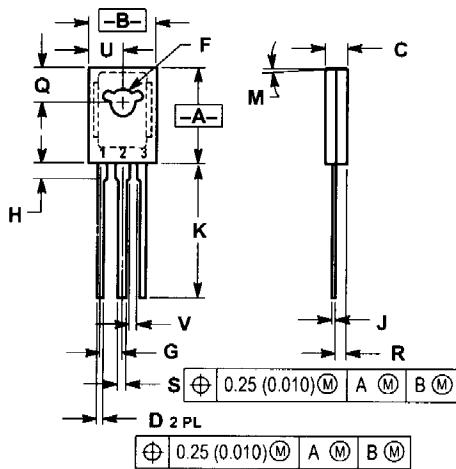


Figure 3. "On" Voltages



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094	BSC	2.39	BSC
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.055	1.15	1.39
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	—	1.02	—

STYLE 1:

- PIN 1. Emitter
2. Collector
3. Base